1N91 thru 1N93



Low-current germanium rectifiers for applications requiring extremely low forward voltage drop, low power dissipation, and high rectification efficiency, such as biasing and battery charging circuits.

MAXIMUM RATINGS+

Rating	Symbol	1N91	1N92	1N93	Unit
Peak Repetitive Reverse Voltage (Rated I _O , T _A ≤ 55°C, see Figure 2)	V _{RM(rep)}	100	200	300	Volts
DC Blocking Voltage T _A ≤ 80°C	v _R	100	200	300	Volts
DC Blocking Voltage $\frac{T_A \le 80^{\circ} C}{T_A \ge 80^{\circ} C}$		Derate V _R 6.7%/°C above 80°C			
Average Rectified Forward Current (Single Phase, Resistive Load, 60 Hz) $\frac{T_A = 55^{\circ}\text{C}, \ 100\% \ \text{V}_{RM}}{T_A = 75^{\circ}\text{C}, \ 50\% \ \text{V}_{RM}}$	IO	1.0		Amp	
$T_A = 75^{\circ}C, 50\% V_{RM}$			0. 25		
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions, see Figure 4)	I FM(surge)	30		Amp	
Operating Junction Temperature Range	Т _Ј	-65 to +95		°C	
Storage Temperature Range	T _{stg}	-65 to +125		°C	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient 1 inch Leads 1/4 inch Leads	$\theta_{ m JA}$	100	°C/ W

ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Peak Forward Voltage Drop (1 _F = 150 mAdc, T _A = 25°C, see Figure 1)	v _F	0. 45	Volts
DC Reverse Current (Rated V _R , T _A = 25°C, see Figure 3)	IR	0. 22	mA

These ratings and characteristics as specified may surpass those specified in the original JEDEC registration for these device types.







